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	First Named Inventor Toshiharu Furukawa et al. Art Unit 2814			
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	First Named Inventor Tos		oshiharu Furukawa et al.	
	Art Unit		2814	
	Examiner Name	Phat X. Cao		
	Attorney Docket Numb	er	ROC920030272US1-IBM273	

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Application Number		10767039		
Filing Date		2004-01-29		
First Named Inventor Toshi		haru Furukawa et al.		
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Attorney Docket Number		ROC920030272US1-IBM273		

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